

# Product Document

# TMD2725

## ALS, and Small Aperture Proximity Sensor Module

### General Description

The device features advanced proximity measurement and digital ambient light sensing (ALS). The package has been designed to accommodate a single small aperture approach. The slim module incorporates an IR LED and factory calibrated LED driver. The proximity detection feature provides object detection (e.g. mobile device screen to user's ear) by photodiode detection of reflected IR energy (sourced by the integrated LED). Detect/release events are interrupt driven, and occur when proximity result crosses upper and/or lower threshold settings. The proximity engine features offset adjustment registers to compensate for unwanted IR energy reflection at the sensor. Proximity results are further improved by automatic ambient light subtraction. The ALS detection feature provides photopic light intensity data. The ALS photodiode has UV and IR blocking filters and a dedicated data converter producing 16-bit data. This architecture allows applications to accurately measure ambient light which enables devices to calculate illuminance to control display backlight.

[Ordering Information](#) and [Content Guide](#) appear at end of datasheet.

### Key Benefits & Features

The benefits and features of TMD2725, ALS, and Small Aperture Proximity Sensor Module are listed below:

**Figure 1:**  
Added Value of Using TMD2725

Benefits	Features
<ul style="list-style-type: none"><li>• Small aperture requirements</li></ul>	<ul style="list-style-type: none"><li>• 1.055mm emitter to detector distance</li></ul>
<ul style="list-style-type: none"><li>• Single device integrated optical solution</li></ul>	<ul style="list-style-type: none"><li>• ALS + proximity</li><li>• 2mm x 3.65mm x 1mm</li><li>• Integrated IR LED</li><li>• Power management features</li><li>• I<sup>2</sup>C fast mode interface compatible</li></ul>
<ul style="list-style-type: none"><li>• Accurate ambient light sensing</li></ul>	<ul style="list-style-type: none"><li>• Photopic Ambient Light Sensor (ALS)</li><li>• UV / IR blocking filters</li><li>• Programmable gain and integration time</li></ul>
<ul style="list-style-type: none"><li>• Reduced power consumption</li></ul>	<ul style="list-style-type: none"><li>• 1.8V power supply with 1.8V I<sup>2</sup>C bus</li></ul>

## Applications

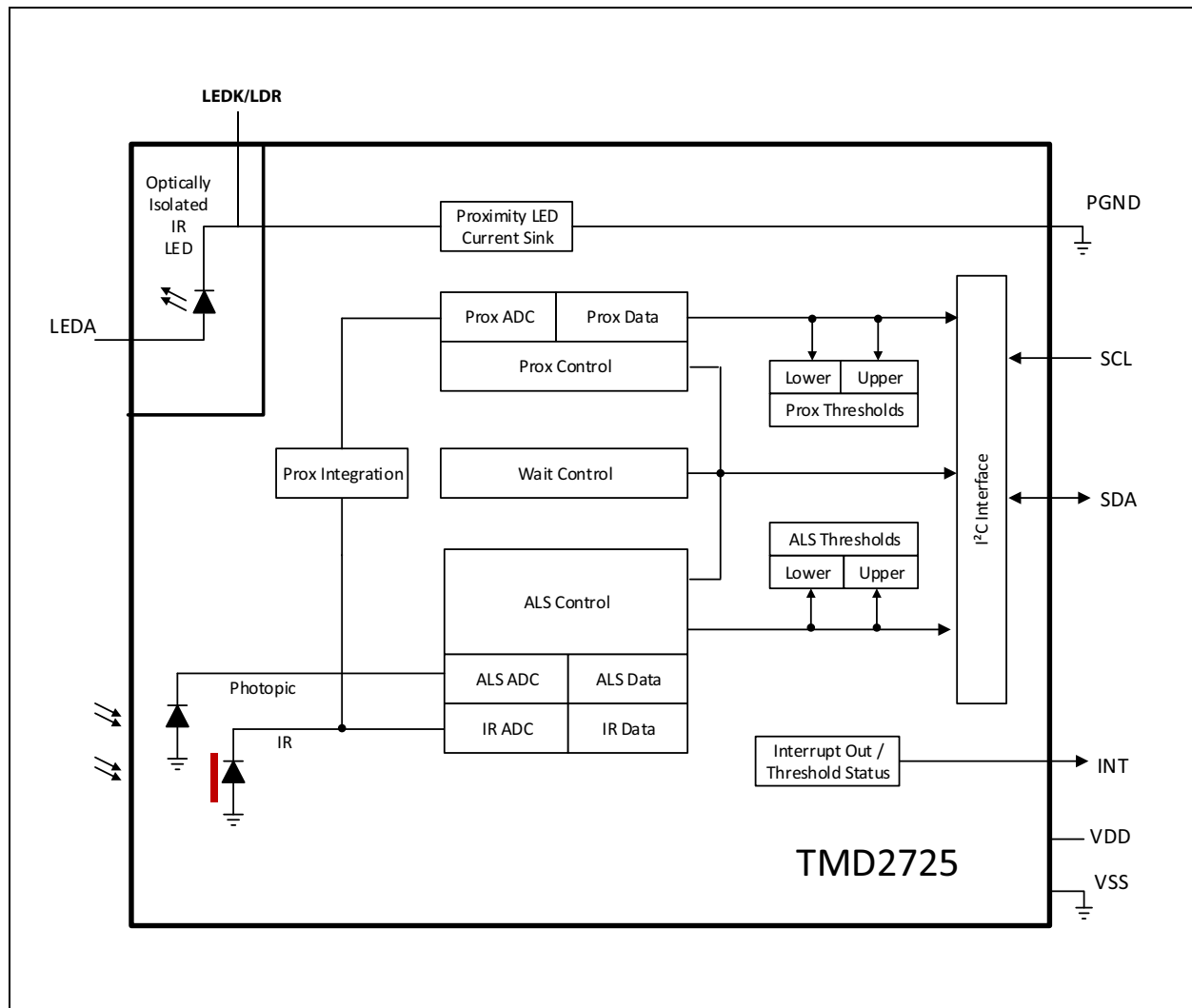
The TMD2725 applications include:

- Ambient light sensing
- Single hole proximity sensing
- Mobile phone touch screen disable

## Block Diagram

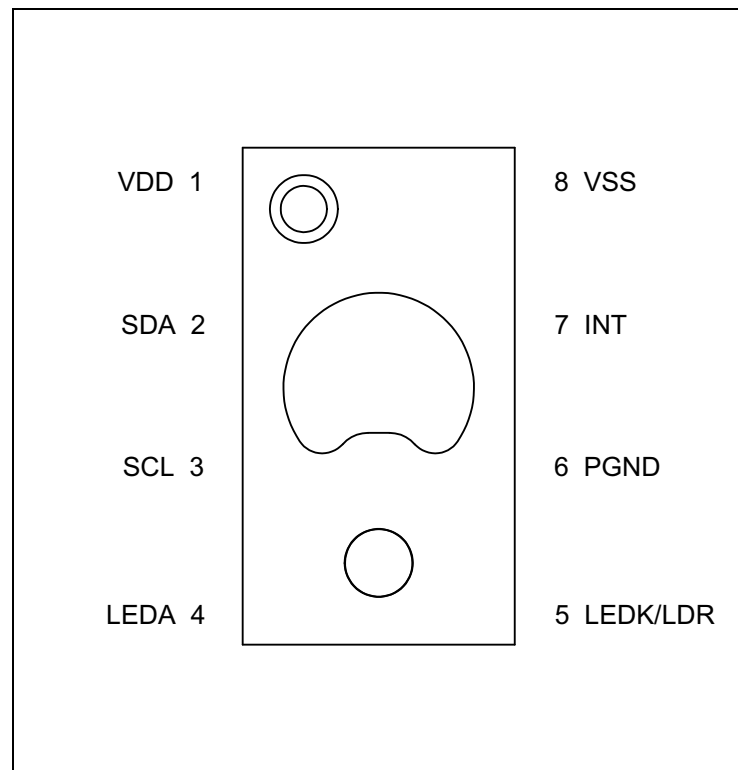
The functional blocks of this device are shown below:

**Figure 2:**  
**Functional Blocks of TMD2725**



## Pin Assignments

**Figure 3:**  
Pin Diagram of TMD2725



**Figure 4:**  
Pin Description of TMD2725 (8-Pin Module)

Pin Number	Pin Name	Description
1	VDD	Supply voltage
2	SDA	I <sup>2</sup> C serial data I/O terminal
3	SCL	I <sup>2</sup> C serial clock input terminal
4	LEDA	LED anode
5	LEDK/LDR	This test point is the junction of the LED cathode and internal current source. Do not connect.
6	PGND	Ground for LED current sink and digital core
7	INT	Interrupt. Open drain output (active low)
8	VSS	Ground. All voltages are referenced to GND

## Absolute Maximum Ratings

Stresses beyond those listed under [Absolute Maximum Ratings](#) may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under [Electrical Characteristics](#) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Figure 5:**  
**Absolute Maximum Ratings**

Symbol	Parameter	Min	Max	Units	Comments
Electrical Parameters					
VDD	Supply Voltage to Ground	-0.3	2.2	V	
LEDA	LED Voltage to PGND	-0.3	3.6	V	
V <sub>IO</sub>	Digital I/O terminal voltage	-0.3	3.6	V	
I <sub>IO</sub>	SDA, INT Output terminal current	-1	20	mA	
Electrostatic Discharge					
I <sub>SCR</sub>	Input Current (latch up immunity) JEDEC JESD78D	± 100		mA	Class II
ESD <sub>HBM</sub>	Electrostatic Discharge HBM JS-001-2014	± 2000		V	
ESD <sub>CDM</sub>	Electrostatic Discharge CDM JEDEC JESD22-C101F	± 500		V	
Temperature Ranges and Storage Conditions					
T <sub>STRG</sub>	Storage Temperature Range	-40	85	°C	
T <sub>BODY</sub>	Package Body Temperature		260	°C	IPC/JEDEC J-STD-020 The reflow peak soldering temperature (body temperature) is specified according to IPC/JEDEC J-STD-020 “Moisture/Reflow Sensitivity Classification for Non-hermetic Solid State Surface Mount Devices.”
RH <sub>NC</sub>	Relative Humidity (non-condensing)	5	85	%	
MSL	Moisture Sensitivity Level	3			Maximum floor life time 168 hours

## Electrical Characteristics

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

**Figure 6:**  
**Recommended Operating Conditions**

Parameter	Min	Typ	Max	Unit
V <sub>DD</sub> supply range	1.7	1.8	2.0	V
V <sub>LEDA</sub> , Supply voltage range <sup>(1)</sup>	3.0	3.3	3.6	V
T <sub>A</sub> , Operating free-air temperature <sup>(2)</sup>	-30		85	°C

**Note(s):**

1. The minimum required supply voltage on the LED anode (V<sub>LEDA</sub>) is the sum of the LED's V<sub>F</sub> and the voltage drop from the LDR pin to PGND pin. The minimum required V<sub>LEDA</sub> can be lowered to 2.8V if the LED's forward current doesn't exceed 102mA (PLDRIVE value of 16 or less).
2. While the device is operational across the temperature range, performance will vary with temperature. Operational characteristics are at 25°C, unless otherwise noted.

**Figure 7:**  
**Operating Characteristics, V<sub>DD</sub> = 1.8V, T<sub>A</sub> = 25°C (unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f <sub>OSC</sub>	Oscillator frequency			8.107		MHz
IDD	Supply Current <sup>(1)</sup>	Active ALS State (PON=AEN=1, PEN=0) <sup>(2)</sup>		80	150	µA
		Idle State (PON=1, AEN=PEN=0) <sup>(3)</sup>		30	60	
		Sleep State <sup>(4)</sup>		0.7	5	
VOL	INT, SDA output low voltage	6mA sink current			0.6	V
ILEAK	Leakage current, SDA,SCL,INT		-5		5	µA
VIH	SCL, SDA input high voltage		1.26		3.3	V
VIL	SCL, SDA input low voltage		0		0.54	V
T <sub>Active</sub>	Time from power-on to ready to receive I <sup>2</sup> C commands			1.5		ms

**Note(s):**

1. Values are shown at the VDD pin and do not include current through the IR LED.
2. This parameter indicates the supply current during periods of ALS integration. If Wait is enabled (WEN=1), the supply current is lower during the Wait period.
3. Idle state occurs when PON=1 and all functions are not enabled.
4. Sleep state occurs when PON = 0 and I<sup>2</sup>C bus is idle. If Sleep state has been entered as the result of operational flow, SAI = 1, PON will remain high.

## Typical Operating Characteristics

**Figure 8:**  
Optical Characteristics, VDD = 1.8V, T<sub>A</sub> = 25°C (unless otherwise noted)

Parameter	Conditions	Clear Channel			Unit
		Min	Typ	Max	
Re Irradiance responsivity  Settings: AGAIN = 16x ATIME = 400ms	$\lambda_D = 465 \text{ nm LED}, 53.8 \mu\text{W}/\text{cm}^2$		58		count/ ( $\mu\text{W}/\text{cm}^2$ )
	$\lambda_D = 530 \text{ nm LED}, 43.9 \mu\text{W}/\text{cm}^2$		490		
	$\lambda_D = 620 \text{ nm LED}, 37.5 \mu\text{W}/\text{cm}^2$		405		
	Warm White LED, 45.6 $\mu\text{W}/\text{cm}^2$		363		
	Warm White LED, 45.6 $\mu\text{W}/\text{cm}^2$	14025	16500	18975	counts
	$\lambda_D = 950 \text{ nm LED}, 21.1 \mu\text{W}/\text{cm}^2$		8		count/ ( $\mu\text{W}/\text{cm}^2$ )

**Figure 9:**  
ALS Optical Characteristics, VDD = 1.8V, T<sub>A</sub> = 25°C (unless otherwise noted)

Parameter	Conditions	Min	Typ	Max	Unit
Integration time step size		2.72	2.82	2.94	ms
Dark ADC count value	E <sub>e</sub> = 0 $\mu\text{W}/\text{cm}^2$ AGAIN: 64x ATIME = 100ms (0x23)	0	1	3	counts
Gain Scaling, relative to 1x gain setting	AGAIN = 1x		1		x
	AGAIN = 4x		4		
	AGAIN = 16x		16		
	AGAIN = 64x		66		
	AGAIN = 128x		140		
ADC noise	AGAIN = 16x		0.005		% full scale

**Figure 10:**  
**Proximity Optical Characteristics, VDD = 1.8V, T<sub>A</sub> = 25°C (unless otherwise noted)**

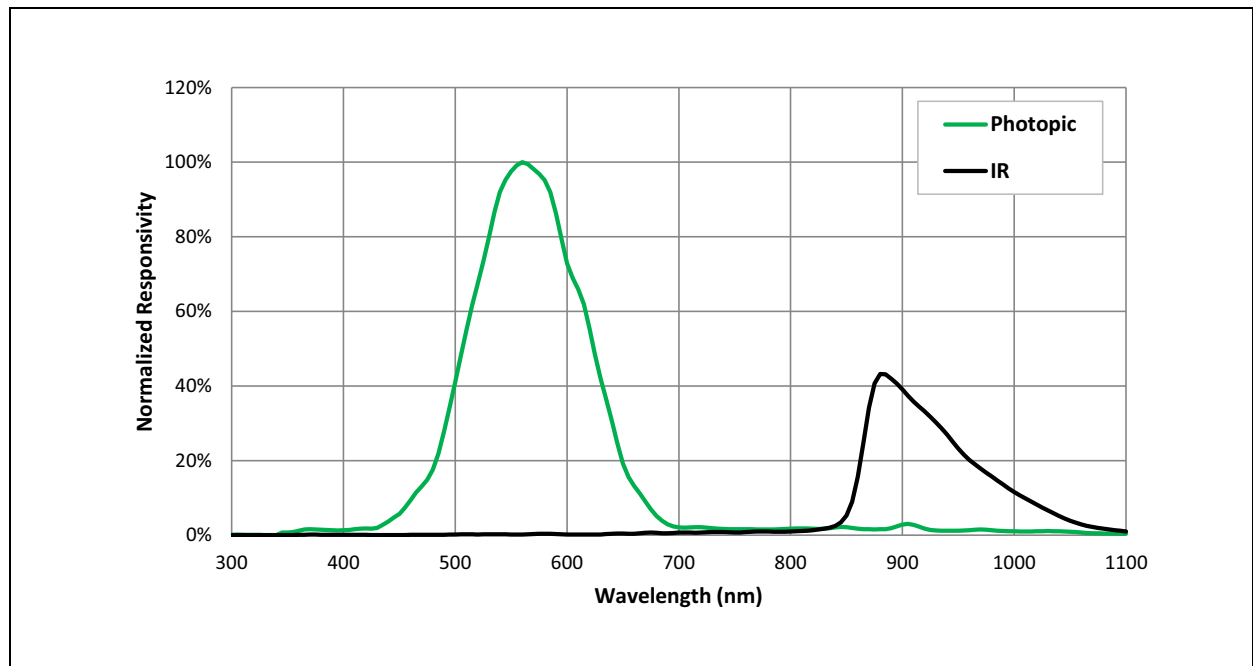
Parameter	Conditions	Min	Typ	Max	Unit
Part to part variation <sup>(1)</sup>	Conditions: PGAIN = 2 (4x) PLDRIVE = 8 (54mA) PPULSE = 15 (16 pulses) PPULSE_LEN = 1 (8μs) d=23mm round target 30mm target distance	75	100	125	%
Response, absolute	Basic proximity measurement <sup>(2)</sup> Conditions: PGAIN = 2 (4x), PLDRIVE = 16 (102mA) PPULSE = 15 (16 pulses) PPULSE_LEN = 2 (16μs) Target material: 90% reflective surface of Kodak gray card Target Size: 100mm x 100mm Target Distance: 100mm	128	160	192	counts
Response, no target	PGAIN = 2 (4x) ILED DRIVE = 16 (102mA) PPULSE = 16 (17 Pulses) Pulse Length = 2 (16μs)	0		20	
Noise/Signal <sup>(3)</sup>	PGAIN = 2 (4x) IRLED DRIVE = 8 (54mA) PPULSE = 15 (16 pulses) PPULSE_LEN = 1 (8μs) d=23mm round target 30mm target distance			1.2	%

**Note(s):**

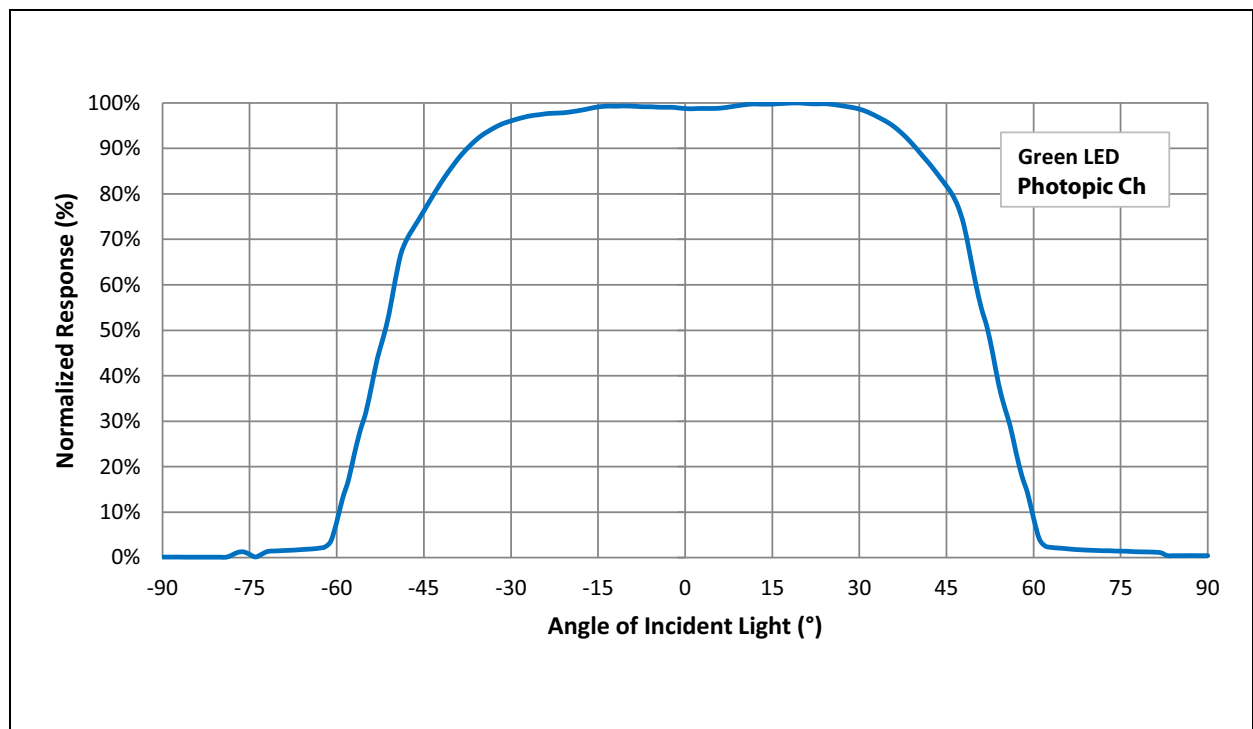
1. Production tested result is the average of 5 readings expressed relative to a calibrated response.
2. Representative result by characterization.
3. Production tested result is the average of 20 readings divided by the maximum proximity value 255.



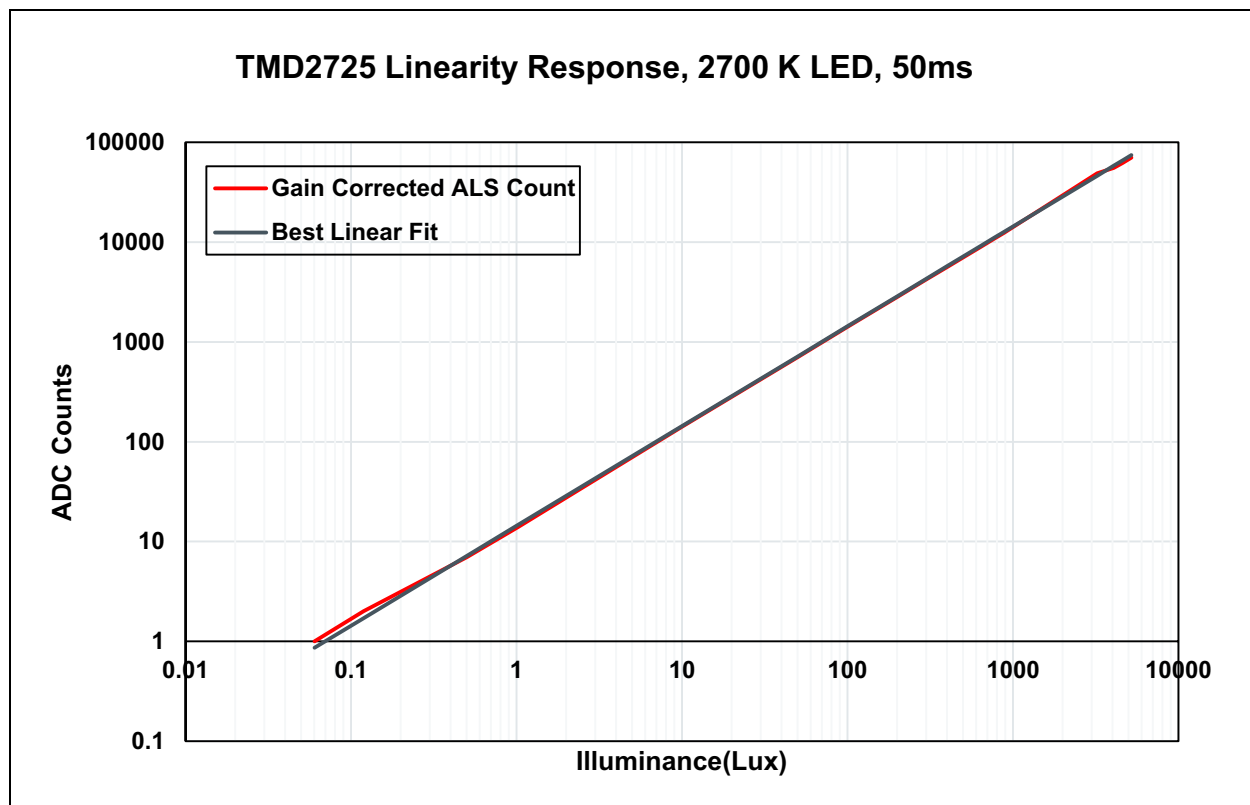
**Figure 11:**  
Spectral Responsivity



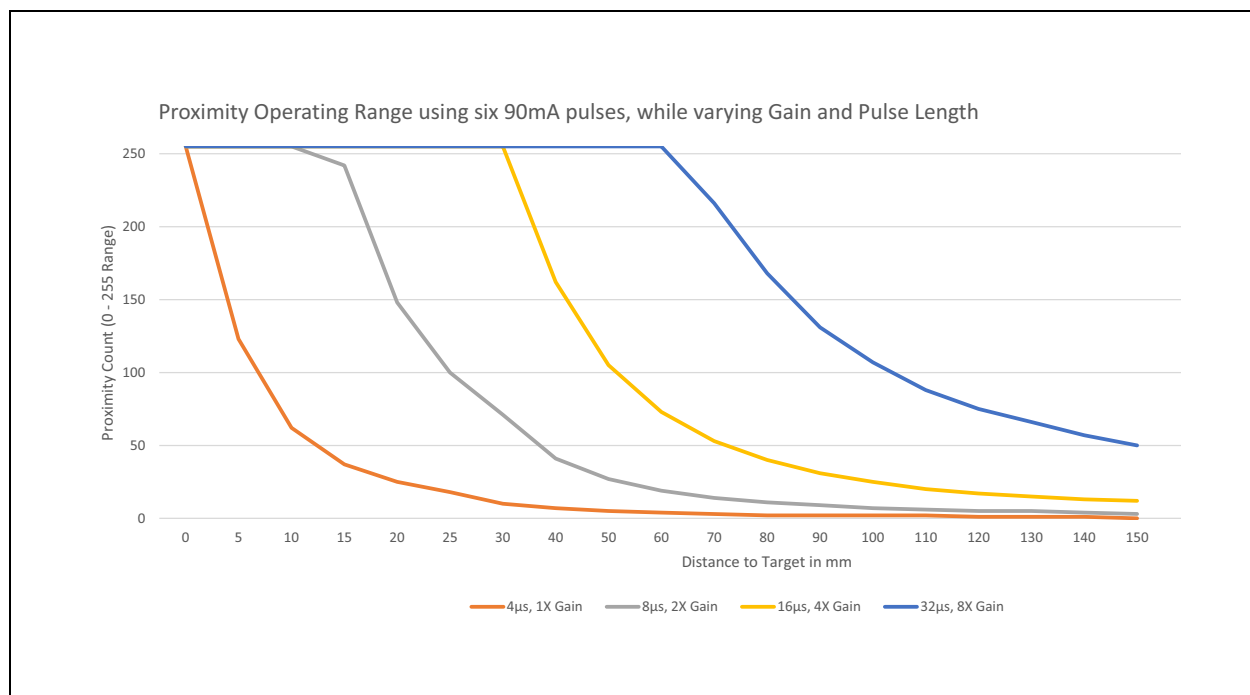
**Figure 12:**  
ALS Responsivity vs. Angular Displacement



**Figure 13:**  
ALS Linearity



**Figure 14:**  
Proximity Operation of TMD2725



**Proximity Operation:** By varying Gain, LED drive current, number of LED pulses and LED pulse duration the proximity detection range can be adjusted.

## Detailed Description

### Proximity

Proximity results are affected by three fundamental factors: the integrated IR LED emission, IR reception, and environmental factors, including target distance and surface reflectivity.

The IR reception signal path begins with IR detection from a photodiode and ends with the 8-bit proximity result in PDATA register. Signal from the photodiode is amplified, and offset adjusted to optimize performance. Offset correction or cross-talk compensation is accomplished by adjustment to the POFFSET register.

The analog circuitry of the device applies the offset value as a subtraction to the signal accumulation; therefore a positive offset value has the effect of decreasing the results.

### Ambient Light Sensing, ALS

The ALS reception signal path begins as photodiodes receive filtered light and ends with the 16-bit results in the PHOTOPICL/H and ALS\_IRL/H registers. The Photopic photodiode is filtered with a UV and IR filter. The ALS\_IR photodiode is filtered to receive only IR. Signal from the photodiodes simultaneously accumulate for a period of time set by the value in ATIME before the results are available. Gain is adjustable from 1x to 64x to facilitate operation over a wide range of lighting conditions. Custom LUX equations are used to calculate the amount of ambient light, as well as, determine the light type (e.g. LED, fluorescent, incandescent, etc.) using the two ALS results.

### I<sup>2</sup>C Characteristics

The device uses I<sup>2</sup>C serial communication protocol for communication. The device supports 7-bit chip addressing and both standard and fast clock frequency modes with a chip address of 0x39. Read and Write transactions comply with the standard set by Philips (now NXP).

Internal to the device, an 8-bit buffer stores the register address location of the desired byte to read or write. This buffer auto-increments upon each byte transfer and is retained between transaction events (i.e. valid even after the master issues a STOP command and the I<sup>2</sup>C bus is released). During consecutive Read transactions, the future/repeated I<sup>2</sup>C Read transaction may omit the memory address byte normally following the chip address byte; the buffer retains the last register address + 1.

### ***I<sup>2</sup>C Write Transaction***

A Write transaction consists of a START, CHIP-ADDRESS WRITE, REGISTER-ADDRESS, DATA BYTE(S), and STOP. Following each byte (9TH clock pulse) the slave places an ACKNOWLEDGE/NOT-ACKNOWLEDGE (ACK/NACK) on the bus. If NACK is transmitted by the slave, the master may issue a STOP.

### ***I<sup>2</sup>C Read Transaction***

A Read transaction consists of a START, CHIP-ADDRESS WRITE, REGISTER-ADDRESS, START, CHIP-ADDRESS READ, DATA BYTE(S), and STOP. Following all but the final byte the master places an ACK on the bus (9TH clock pulse). Termination of the Read transaction is indicated by a NACK being placed on the bus by the master, followed by STOP.

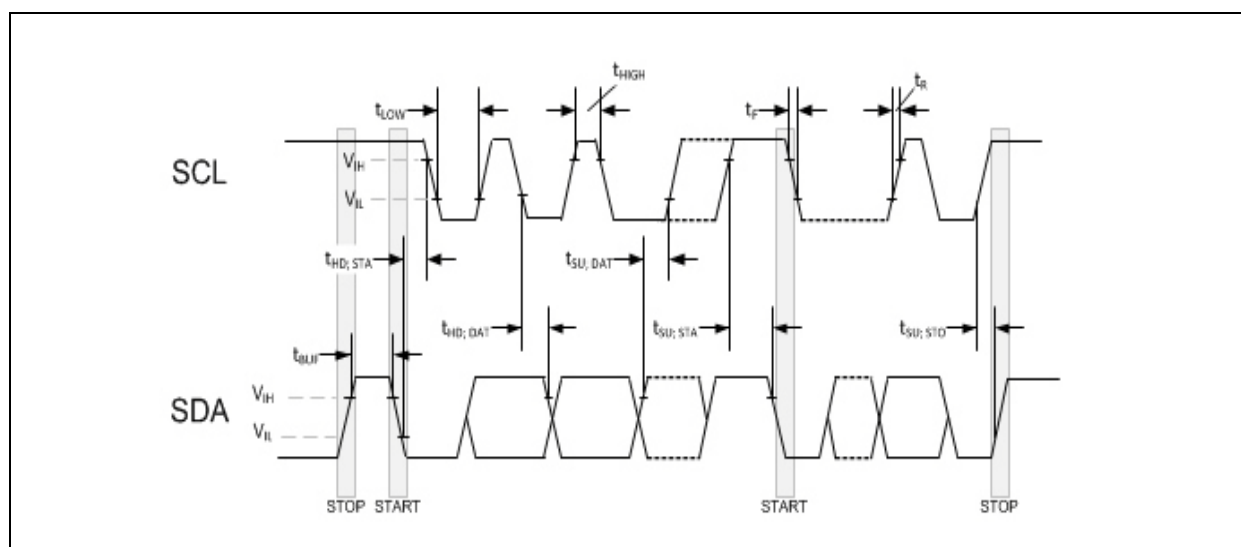
Alternately, if the previous I<sup>2</sup>C transaction was a Read, the internal register address buffer is still valid, allowing the transaction to proceed without “re”-specifying the register address. In this case the transaction consists of a START, CHIP-ADDRESS<sub>READ</sub>, DATA BYTE(S), and STOP. Following all but the final byte the master places an ACK on the bus (9TH clock pulse). Termination of the Read transaction is indicated by a NACK being placed on the bus by the master, followed by STOP.

The I<sup>2</sup>C bus protocol was developed by Philips (now NXP). For a complete description of the I<sup>2</sup>C protocol, please review the NXP I<sup>2</sup>C design specification at:

<https://www.i2c-bus.org/references/>

## **Timing Diagrams**

**Figure 15:**  
**I<sup>2</sup>C Timing**

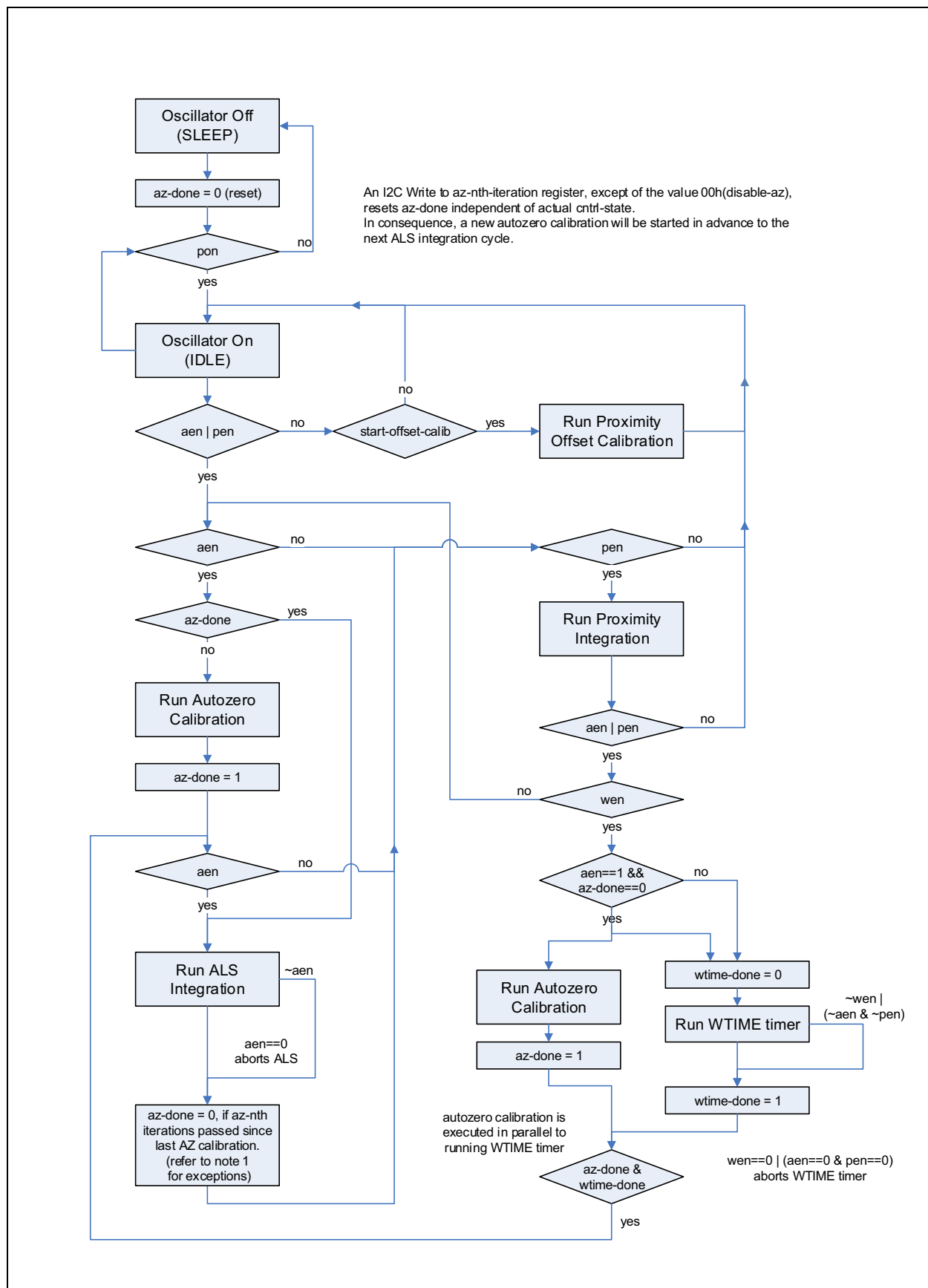


## Principles of Operation

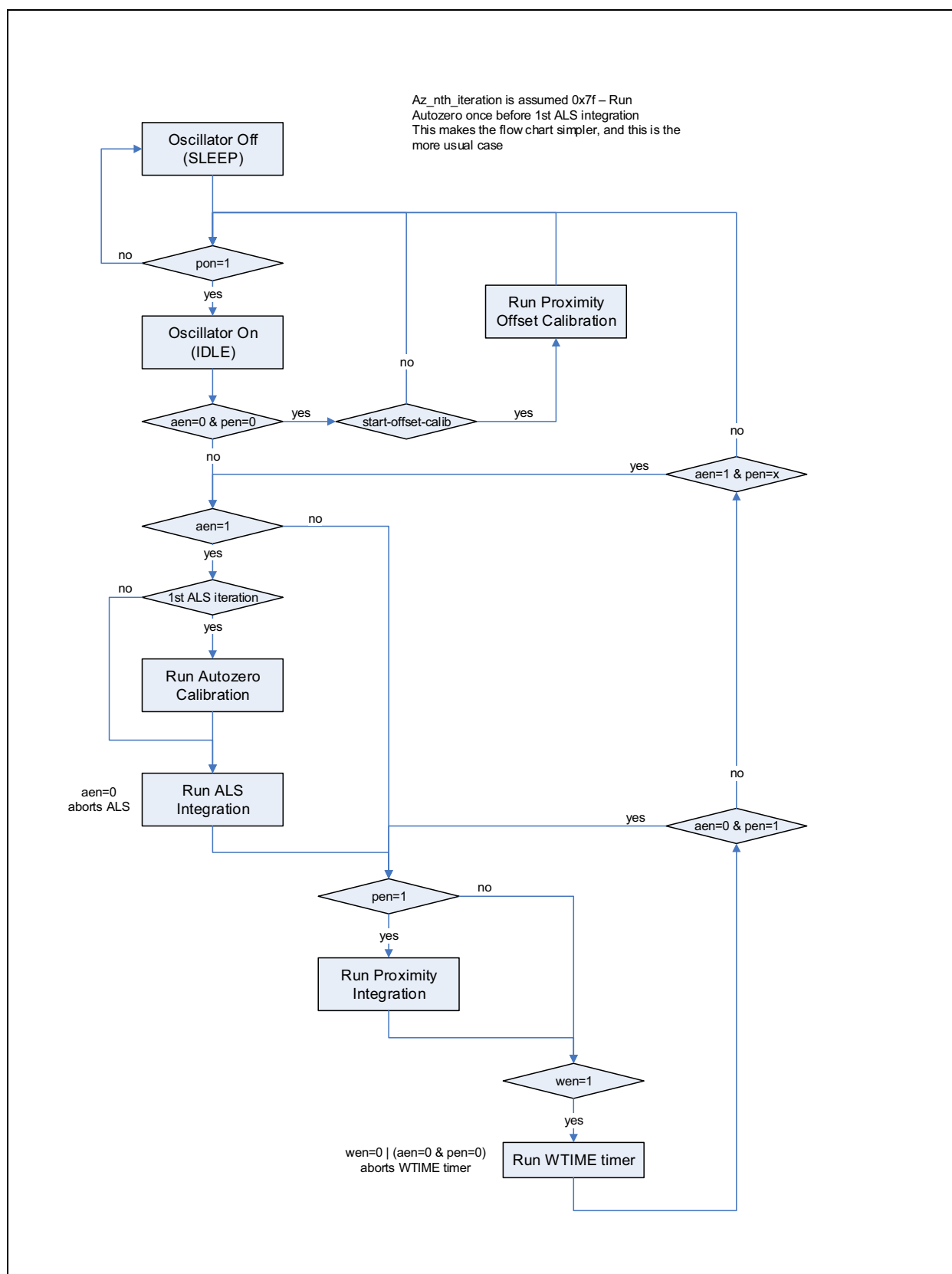
### System State Machine

An internal state machine provides system control of the ALS, proximity detection, and power management features of the device. At power up, an internal power-on-reset initializes the device and puts it in a lowpower Sleep state. When a write on I<sup>2</sup>C bus to the Enable register (0x80) PON bit is set, the device transitions to the Idle state. If PON is disabled, the device will return to the Sleep state to save power. Otherwise, the device will remain in the Idle state until a Proximity or ALS function is enabled. Once enabled, the device will execute the ALS, Proximity and Wait states in sequence as indicated in [Figure 16](#) and [Figure 17](#). Upon completion, the device will automatically begin a new ALS-Prox-Wait cycle as long as PON and either PEN or AEN remain enabled. If the Prox or ALS function generates an interrupt and the Sleep-After-Interrupt (SAI) feature is enabled, the device will transition to the Sleep state and remain in a low-power mode until an I<sup>2</sup>C command is received clearing the interrupts in the STATUS register. See Interrupts for additional information.

### Figure 16: Detailed State Diagram



### Figure 17: Simplified State Diagram



## Register Description

### Register Overview

**Figure 18:**  
Register Overview

Address	Register Name	R/W	Register Function	Reset Value
0x80	ENABLE	R/W	Enables states and functions	0x00
0x81	ATIME	R/W	ALS integration time	0x00
0x82	PRATE	R/W	Proximity sampling time	0x1F
0x83	WTIME	R/W	Wait time	0x00
0x84	AILTL	R/W	ALS interrupt low threshold low byte	0x00
0x85	AILTH	R/W	ALS interrupt low threshold high byte	0x00
0x86	AIHTL	R/W	ALS interrupt high threshold low byte	0x00
0x87	AIHTH	R/W	ALS interrupt high threshold high byte	0x00
0x88	PILT	R/W	Proximity interrupt low threshold	0x00
0x8A	PIHT	R/W	Proximity interrupt high threshold	0x00
0x8C	PERS	R/W	Interrupt persistence filters	0x00
0x8D	CFG0	R/W	Configuration register zero	0x80
0x8E	PCFG0	R/W	Proximity configuration register zero	0x4F
0x8F	PCFG1	R/W	Proximity configuration register one	0x80
0x90	CFG1	R/W	Configuration register one	0x00
0x91	REVID	R	Revision ID	0x20
0x92	ID	R	Device ID	0xE4
0x93	STATUS	R	Device status register	0x00
0x94	PHOTOPICL	R	Photopic channel data low byte	0x00
0x95	PHOTOPICH	R	Photopic channel data high byte	0x00
0x96	ALS_IRL	R	IR channel data low byte	0x00
0x97	ALS_IRH	R	IR channel data high byte	0x00
0x9C	PDATA	R	Proximity channel data	0x00
0x9E	REVID2	R	Auxiliary ID	0x00
0x9F	CFG2	R/W	Configuration register two	0x04
0xAB	CFG3	R/W	Configuration register three	0x4C



Address	Register Name	R/W	Register Function	Reset Value
0xC0	POFFSETL	R/W	Proximity offset magnitude	0x00
0xC1	POFFSETH	R/W	Proximity offset sign	0x00
0xD6	AZ_CONFIG	R/W	Autozero configuration	0x7F
0xD7	CALIB	R/W	Calibration start	0x00
0xD9	CALIBCFG	R/W	Calibration configuration	0x50
0xDC	CALIBSTAT	R/W	Calibration status	0x00
0xDD	INTENAB	R/W	Interrupt enables	0x00

**Note(s):**

1. Address 0x98 and 0x99 will contain the results for the IR photodiode when controlled by the Green/IR MUX.

Register Access:

R = Read Only

W = Write Only

R/W = Read or Write

SC = Self Clearing after access

## Detailed Register Description

### *Enable Register (Address 0x80)*

**Figure 19:**  
**Enable Register**

Addr: 0x80		Enable		
Bit	Bit Name	Default	Access	Bit Description
7:4	RESERVED	0000	RW	Reserved.
3	WEN	0	RW	This bit activates the wait feature. Active high.
2	PEN	0	RW	This bit activates the proximity detection. Active high.
1	AEN	0	RW	This bit activates the ALS function. Active high. *Set AEN=1 and PON=1 in the same command to ensure auto-zero function is run prior to the first measurement.
0	PON	0	RW	This field activates the internal oscillator and ADC channels. Active high.

Before activating AEN or PEN, preset each applicable operating mode registers and bits.

### ATIME Register (Address 0x81)

Figure 20:  
ATIME Register

Addr: 0x81		ATIME					
Bit	Bit Name	Default	Access	Bit Description			
7:0	ATIME	0x00	RW	ALS value that specifies the integration time in 2.78ms intervals. 0x00 indicates 2.8ms. The maximum ALS value depends on the integration time. For every 2.78ms, the maximum value increases by 1024. This means that to be able to reach ALS full scale, the integration time has to be at least 64*2.8ms.			
				Value	Integration Cycles	Integration Time	Maximum ALS Value
				0x00	1	2.8ms	1023
				0x01	2	5.6ms	2047
				...	...	...	...
				0x3F	64	180ms	65535
				...	...	...	...
				0xFF	256	719ms	65535

The ATIME register controls the integration time of the ALS ADCs. The timer is implemented with a down counter with 0x00 as the terminal count. The timer is clocked at a 2.8ms nominal rate. Loading 0x00 will generate a 2.8ms integration time, loading 0x01 will generate a 5.6ms integration time, and so forth. The RC oscillator runs at 8MHz nominal rate. This gets divided by 11 to generate the integration clock of 727kHz. One count in ATIME (nominal 2.8ms) are 2.78ms. This is 2048 integration clock cycles:  $125\text{ns} * 11 * 8 * 256 = 2.8\text{ms}$ .

### PTIME Register (Address 0x82)

Figure 21:  
PTIME Register

Addr: 0x82		PTIME			
Bit	Bit Name	Default	Access	Bit Description	
7:0	PTIME	0x1F	RW	This register defines the duration of 1 Prox Sample, which is $(PTIME + 1) * 88\mu\text{s}$ .	

**WTIME Register (Address 0x83)****Figure 22:**  
**WTIME Register**

Addr: 0x83		WTIME				
Bit	Bit Name	Default	Access	Bit Description		
7:0	WTIME	0x00	RW	Value that specifies the wait time between ALS cycles in 2.78ms increments.		
				Value	Increments	Wait Time
				0x00	1	2.8ms (33.8ms)
				0x01	2	5.6ms (67.6ms)
				...	...	...
				0x3F	64	180ms (2.16s)
				...	...	...
				0xFF	256	719ms (8.65s)

The wait timer is implemented using a down counter.  
 Wait time = (value + 1) x 2.8ms. If WLONG is enabled then  
 Wait time = (value + 1) x 2.8ms. x 12.

**AILTL Register (Address 0x84)****Figure 23:**  
**AILTL Register**

Addr: 0x84		AILTL				
Bit	Bit Name	Default	Access	Bit Description		
7:0	AILTL	0x00	RW	This register sets the low byte of the LOW ALS threshold.		

The photopic channel is compared against low-going 16-bit threshold value set by AILTL and AILTH.

### ***AILTH Register (Address 0x85)***

**Figure 24:**  
**AILTH Register**

Addr: 0x85		AILTH		
Bit	Bit Name	Default	Access	Bit Description
7:0	AILTH	0x00	RW	This register sets the high byte of the LOW ALS threshold.

The photopic channel is compared against low-going 16-bit threshold value set by AILTL and AILTH.

The contents of the AILTH and AILTL registers are combined and treated as a sixteen bit threshold value. If the value generated by the photopic channel is below the AILTL/H threshold and the APERS value is reached, the AINT bit is asserted. If AIEN is set, then the INT pin will also assert.

When setting the 16-bit ALS threshold AILTL must be written first, immediately follow by AILTH. Internally, the lower 8-bits are buffered until the upper 8-bits are written. As the upper 8-bits are written both the high and low bytes are simultaneously latched as a 16-bit value.

### ***AIHTL Register (Address 0x86)***

**Figure 25:**  
**AIHTL Register**

Addr: 0x86		AIHTL		
Bit	Bit Name	Default	Access	Bit Description
7:0	AIHTL	0x00	RW	This register sets the low byte of the HIGH ALS threshold.

The photopic channel is compared against high-going 16-bit threshold value set by AIHTL and AIHTH.

The contents of the AIHTH and AIHTL registers are combined and treated as a sixteen bit threshold value. If the value generated by the photopic channel is above the AIHTL/H threshold and the APERS value is reached, the AINT bit is asserted. If AIEN is set, then the INT pin will also assert. When setting the 16-bit ALS threshold AIHTL must be written first, immediately follow by AIHTH. Internally, the lower 8-bits are buffered until the upper 8-bits are written. As the upper 8-bits are written both the high and low bytes are simultaneously latched as a 16-bit value.

**AIHTH Register (Address 0x87)****Figure 26:**  
**AIHTH Register**

Addr: 0x87		AIHTH		
Bit	Bit Name	Default	Access	Bit Description
7:0	AIHTH	0x00	RW	This register sets the high byte of the HIGH ALS threshold.

The photopic channel is compared against high-going 16-bit threshold value set by AIHTL and AIHTH.

The contents of the AIHTH and AIHTL registers are combined and treated as a sixteen bit threshold value. If the value generated by the photopic channel is above the AIHTL/H threshold and the APERS value is reached, the AINT bit is asserted. If AIEN is set, then the INT pin will also assert.

When setting the 16-bit ALS threshold AIHTL must be written first, immediately follow by AIHTH. Internally, the lower 8-bits are buffered until the upper 8-bits are written. As the upper 8-bits are written both the high and low bytes are simultaneously latched as a 16-bit value.

**PILT Register (Address 0x88)****Figure 27:**  
**PILT Register**

Addr: 0x88		PILT		
Bit	Bit Name	Default	Access	Bit Description
7:0	PILT	0x00	RW	This register sets the Proximity ADC channel low threshold.

The proximity channel is compared against low-going 8-bit threshold value set by PILT.

If the value generated by the Proximity channel is below the PILT threshold and the PPERS value is reached, the PINT bit is asserted. If PIEN is set, then the INT pin will also assert.

**PIHT Register (Address 0x8A)****Figure 28:**  
**PIHT Register**

Addr: 0x8A		PIHT		
Bit	Bit Name	Default	Access	Bit Description
7:0	PIHT	0x00	RW	This register sets the Proximity ADC channel high threshold.

The proximity channel is compared against high-going 8-bit threshold value set by PIHT.

If the value generated by the Proximity channel is above the PIHT threshold and the PPERS value is reached, the PINT bit is asserted. If PIEN is set, then the INT pin will also assert.

**PERS Register (Address 0x8C)****Figure 29:**  
**PERS Register**

Addr: 0x8C		PERS			
Bit	Bit Name	Default	Access	Bit Description	
7:4	PPERS	0000	RW	This register sets the Proximity persistence filter.	
				Value	Interrupt
				0	Every Proximity Cycle
				1	Any value outside PILT/PIHT thresholds
				2	2 consecutive proximity values out of range
				3	3 consecutive proximity values out of range
				...	....
				15	15 consecutive proximity values out of range

Addr: 0x8C		PERS			
Bit	Bit Name	Default	Access	Bit Description	
3:0	APERS	0000	RW	This register sets the ALS persistence filter.	
				0	Every ALS Cycle
				1	Any value outside ALS thresholds
				2	2 consecutive ALS values out of range
				3	3 consecutive ALS values out of range
				4	5 consecutive ALS values out of range
				5	10 consecutive ALS values out of range
				6	15 consecutive ALS values out of range
				7	20 consecutive ALS values out of range
				...	...
				13	50 consecutive ALS values out of range
				14	55 consecutive ALS values out of range
				15	60 consecutive ALS values out of range

The frequency of consecutive proximity channel results outside of threshold limits are counted; this count value is compared against the PPERS value. If the counter is equal to the PPERS value an interrupt is asserted. Any time a proximity channel result is inside the threshold values the counter is cleared. The frequency of consecutive photopic channel results outside of threshold limits are counted; this count value is compared against the APERS value. If the counter is equal to the APERS setting an interrupt is asserted. Any time a photopic channel result is inside the threshold values the counter is cleared.



**CFG0 Register (Address 0x8D)****Figure 30:**  
**CFG0 Register**

Addr: 0x8D		CFG0		
Bit	Bit Name	Default	Access	Bit Description
7:3	Reserved	10000	RW	This field must be set to the default value.
2	WLONG	0	RW	When Wait Long is asserted the wait period as set by WTIME is increased by a factor of 12.
1:0	Reserved	00	RW	This field must be set to the default value.

The wait timer is implemented using a down counter.  
Wait time = (value +1) x 2.8ms. If WLONG is enabled then  
Wait time = (value +1) x 2.8ms x 12.

**PCFG0 Register (Address 0x8E)****Figure 31:**  
**PCFG0 Register**

Addr: 0x8E		PCFG0			
Bit	Bit Name	Default	Access	Bit Description	
7:6	PPULSE_LEN	01	RW	Proximity Pulse Length	
				Value	Pulse Length
				0	4μs
				1	8μs
				2	16μs
				3	32μs
5:0	PPULSE	001111	RW	Maximum Number of Pulses in a single proximity cycle.	
				Value	Maximum Number of Pulses
				0	1
				1	2
				2	3
				...	...
				63	64

The PPULSE\_LEN field sets the width of all IR LED pulses within the proximity cycle. Longer pulses result in increased proximity range and typically result in less electrical noise generated in the analog front end. However, a setting of 8μs is recommended because less cumulative noise is generated during a proximity cycle.

The PPULSE field sets the maximum number of IR LED pulses that may occur in a proximity cycle. The proximity engine will automatically continue to add IR LED pulses, up to the value set in PPULSE or if a near-saturation condition occurs.

The dynamic range of the sensor is automatically adjusted to detect distant targets as well as prevent saturation from close targets.

This operation also reduces power consumption because proximity integration period is automatically shortened when a target is either too close or far from the sensor.

### PCFG1 Register (Address 0x8F)

Figure 32:  
PCFG1 Register

Addr: 0x8F		PCFG1				
Bit	Bit Name	Default	Access	Bit Description		
7:6	PGAIN	10	RW	This field sets the gain of the proximity IR sensor.		
				Gain	Value	Bit Field
				1x	0	00b
				2x	1	01b
				4x	2	10b
				8x	3	11b
5	Reserved	0	RW	Reserved		
4:0	PLDRIVE	00000	RW	This field sets the drive strength of the IR LED current. Values are approximate; actual current through LED is factory trimmed to normalize IR intensity.		
				Value	LED Current	
				0	6mA	
				1	12mA	
				i <sub>LED</sub> = 6(PLDRIVE + 1) mA		
				30	186mA	
				31	192mA	

**CFG1 Register (Address 0x90)****Figure 33:**  
**CFG1 Register**

Addr: 0x90		CFG1			
Bit	Bit Name	Default	Access	Bit Description	
7:2	Reserved	000000	RW	Reserved	
1:0	AGAIN	00	RW	This field sets the gain of the ALS sensor.	
				Value	Gain
				0	1x
				1	4x
				2	16x
				3	64x

**REVID Register (Address 0x91)****Figure 34:**  
**REVID Register**

Addr: 0x91		REVID		
Bit	Bit Name	Default	Access	Bit Description
7:3	Reserved	00100	RO	Reserved
2:0	REV_ID	000	RO	Device revision number

**ID Register (Address 0x92)****Figure 35:**  
**ID Register**

Addr: 0x92		ID		
Bit	Bit Name	Default	Access	Bit Description
7:2	ID	111001	RO	Device type identification.
1:0	Reserved	00	RO	Reserved

### Status Register (Address 0x93)

Figure 36:  
Status Register

Addr: 0x93		Status Register		
Bit	Bit Name	Default	Access	Bit Description
7	ASAT	0	R, SC	The Analog Saturation flag signals that the ALS results may be unreliable due to saturation of the AFE.
6	PSAT	0	R, SC	The Proximity Saturation flag indicates that an ambient- or reflective-saturation event occurred during a previous proximity cycle.
5	PINT	0	R, SC	The Proximity Interrupt flag indicates that proximity results have exceeded thresholds and persistence settings.
4	AINT	0	R, SC	The ALS Interrupt flag indicates that ALS results (photopic channel) have exceeded thresholds and persistence settings.
3	CINT	0	R, SC	The Calibration Interrupt flag indicates that calibration has completed.
2	Reserved	0	R, SC	Reserved
1	PSAT_REFLECTIVE	0	R, SC	The Reflective Proximity Saturation Interrupt flag signals that the AFE has saturated during the IR LED active portion of proximity integration.
0	PSAT_AMBIENT	0	R, SC	The Ambient Proximity Saturation Interrupt flag signals that the AFE has saturated during the IR LED inactive portion of proximity integration.

All flags in this register can be cleared by setting the bit high. Alternatively, if the CFG3.int\_read\_clear bit is set, then simply reading this register automatically clears all eight flags.

### PHOTOPICL Register (Address 0x94)

Figure 37:  
PHOTOPICL Register

Addr: 0x94		PHOTOPICL		
Bit	Bit Name	Default	Access	Bit Description
7:0	PHOTOPICL	0x00	RO	This register contains the low byte of the 16-bit photopic channel data.

**PHOTOPICH Register (Address 0x95)**

**Figure 38:**  
**PHOTOPICH Register**

Addr: 0x95		PHOTOPICH		
Bit	Bit Name	Default	Access	Bit Description
7:0	PHOTOPICH	0x00	RO	This register contains the high byte of the 16-bit photopic channel data.

**ALS\_IRL Register (Address 0x96)**

**Figure 39:**  
**ALS\_IRL Register**

Addr: 0x96		ALS_IRL		
Bit	Bit Name	Default	Access	Bit Description
7:0	ALS_IRL	0x00	RO	This register contains the low byte of the 16-bit IR channel data.

**ALS\_IRH Register (Address 0x97)**

**Figure 40:**  
**ALS\_IRH Register**

Addr: 0x97		ALS_IRH		
Bit	Bit Name	Default	Access	Bit Description
7:0	ALS_IRH	0x00	RO	This register contains the high byte of the 16-bit IR channel data.

**PDATA Register (Address 0x9C)**

**Figure 41:**  
**PDATA Register**

Addr: 0x9C		PDATA		
Bit	Bit Name	Default	Access	Bit Description
7:0	PDATA	0x00	RO	This register contains the 8-bit proximity channel data.

**REVID2 Register (Address 0x9E)****Figure 42:**  
**REVID2 Register**

Addr: 0x9E		REVID2		
Bit	Bit Name	Default	Access	Description
7:4	Reserved	0000	RO	Reserved
3:0	REVID2	0000	RO	Package Identification

**CFG2 Register (Address 0x9F)****Figure 43:**  
**CFG2 Register**

Addr: 0x9F		CFG2		
Bit	Bit Name	Default	Access	Bit Description
7:5	Reserved	000	RW	Reserved
4	AGAINMAX	0	RW	This bit adjusts the overall ALS gain factor. See <a href="#">Figure 44</a> for recommended settings and corresponding overall ALS gain factor.
3	Reserved	0	RW	Reserved
2	AGAINL	1	RW	This bit adjusts the overall ALS gain factor. See <a href="#">Figure 44</a> for recommended settings and corresponding overall ALS gain factor.
1:0	Reserved	00	RW	Reserved

The ALS gain can be adjusted using by setting the two AGAIN bits as well as the AGAINL bit which yields an overall range from  $\frac{1}{2} \times$  to  $128 \times$ .

**Figure 44:**  
**AGAIN Range**

AGAIN[1]	AGAIN[0]	AGAINMAX	AGAINL	Overall ALS Gain
0	0	0	0	$\frac{1}{2}$
0	0	0	1	1
0	1	0	1	4
1	0	0	1	16
1	1	0	1	64
1	1	1	1	128

**CFG3 Register (Address 0xAB)**

**Figure 45:**  
**CFG3 Register**

Addr: 0xAB		CFG3			
Bit	Bit Name	Default	Access	Bit Description	
7	INT_READ_CLEAR	0	RW	If the Interrupt-Clear-by-Read bit is set, then all flag bits in the STATUS register will be reset whenever the STATUS register is read over I <sup>2</sup> C.	
6:5	Reserved	10	RW	Reserved	
4	SAI	0	RW	The Sleep After Interrupt bit is used to place the device into a low power mode upon an interrupt pin assertion.	
				<b>PON</b>	<b>Oscillator</b>
				0	OFF
				1	ON
				1	ON
				1	OFF
3:0	Reserved	1100	RW	Reserved	



The SAI bit sets the device operational mode following the completion of an ALS or proximity cycle. If AINT and AIEN are both set or if PINT and PIEN are both set, causing an interrupt on the INT pin, and the SAI bit is set, then the oscillator will deactivate. The Device will appear as if PON = 0, however, PON will read as 1. The device can only be reactivated (oscillator enabled) by clearing the interrupts in the STATUS register.

### ***POFFSETL Register (Address 0xC0)***

**Figure 46:**  
**POFFSETL Register**

Addr: 0xC0		POFFSETL		
Bit	Bit Name	Default	Access	Bit Description
7:0	POFFSETL	0x00	RW	This register contains the magnitude portion of proximity offset adjust value.

Typically, optical and/or electrical crosstalk negatively influence proximity operation and results. The POFFSETL/POFFSETH registers provide a mechanism to remove system crosstalk from the proximity data. POFFSETL and POFFSETH contains the magnitude and sign of a value which adjusts PDATA generated in the AFE. An offset value in the range of  $\pm 255$  is possible.

### ***POFFSETH Register (Address 0xC1)***

**Figure 47:**  
**POFFSETH Register**

Addr: 0xC1		POFFSETH		
Bit	Bit Name	Default	Access	Bit Description
7:1	Reserved	0000000	RW	Reserved
0	POFFSET_SIGN	0	RW	This register contains the sign portion of proximity offset adjust value.

**AZ\_CONFIG Register (Address 0xD6)****Figure 48:**  
**AZ\_CONFIG Register**

Addr: 0xD6		AZ_CONFIG		
Bit	Bit Name	Default	Access	Description
7	Reserved	0	RW	Reserved.
6:0	AZ_NTH_ITERATION	1111111	RW	Run autozero automatically before every nth ALS cycle (00h = never, n = every nth ALS cycle, and 7Fh = only before the first ALS cycle).

**CALIB Register (Address 0xD7)****Figure 49:**  
**CALIB Register**

Addr: 0xD7		CALIB		
Bit	Bit Name	Default	Access	Bit Description
7:6	Reserved	00	RO	Reserved
5	ELECTRICAL_CALIBRATION	0	RW	Selects proximity calibration type. 1 = electrical offset only. 0 = calibration compensates for electrical and optical crosstalk.
4:1	Reserved	0000	RW	Reserved
0	START_OFFSET_CALIB	0	RW	Set to 1 to start a calibration sequence.

Proximity response in systems with electrical and optical crosstalk may be improved by using the calibration feature. Optical crosstalk is caused when the photodiode receives a small portion of the LED IR which was unintentionally reflected by a surface other than the target. Electrical offset is caused by electrical disturbance in the sensor AFE, and also influences the proximity result. The calibration routine adjusts the value in registers C0 and C1 until the proximity result is as close to BINSRCH\_TARGET as possible without becoming zero. Optical and electrical calibration function identically, except that during an electrical calibration the proximity photodiode is disconnected from the AFE.

An electrical only calibration can be initiated by setting the ELECTRICAL\_CALIBRATION and START\_OFFSET\_CALB bits. To perform an optical (and electrical) calibration do not set the ELECTRICAL\_CALIBRATION bit when setting the START\_OFFSET\_CALIB. The CINT flag will assert after calibration has

finished.

Upon completion Proximity offset registers are automatically loaded with calibration result.

### **CALIBCFG Register (Address 0xD9)**

**Figure 50:**  
**CALIBCFG Register**

Addr: 0xD9		CALIBCFG			
Bit	Bit Name	Default	Access	Bit Description	
7:5	BINSRCH_TARGET	010	RW	Proximity Result Target	
				Value	PDATA Target
				0	0
				1	1
				2	3
				3	7
				4	15
				5	31
				6	63
				7	127
4	Reserved	1	RW	Reserved	
3	AUTO_OFFSET_ADJ	0	RW	The Proximity Auto Offset Adjust bit causes the value in POFFSETL register to decrement when PDATA equals zero at the completion of the proximity cycle.	
2:0	PROX_AVG	000	RW	The Proximity Averaging field defines the number of ADC samples collected and averaged during a cycle which become the proximity result.	
				Value	Sample Size
				0	Disable
				1	2
				2	4
				3	8
				4	16
				5	32
				6	64
				7	128

The binary search target field is used by the calibration feature to set the baseline value for PDATA when no target is present. For example, calibration of a device in open air, with no target, and BINSEARCH\_TARGET setting of 4 causes the PDATA value will be approximately 15 counts. This feature is useful because it forces PDATA result to always be above zero.

The PROX\_AVG field sets the number of ADC samples that are averaged to calculate the PDATA result.

### ***CALIBSTAT Register (Address 0xDC)***

**Figure 51:**  
**CALIBSTAT Register**

Addr: 0xDC		CALIBSTAT		
Bit	Bit Name	Default	Access	Bit Description
7:1	Reserved	0000000	RW	Reserved
0	CALIB_FINISHED	0	RW	This flag indicates that calibration has finished. It can only be cleared by setting this bit high.

### ***INTENAB Register (Address 0xDD)***

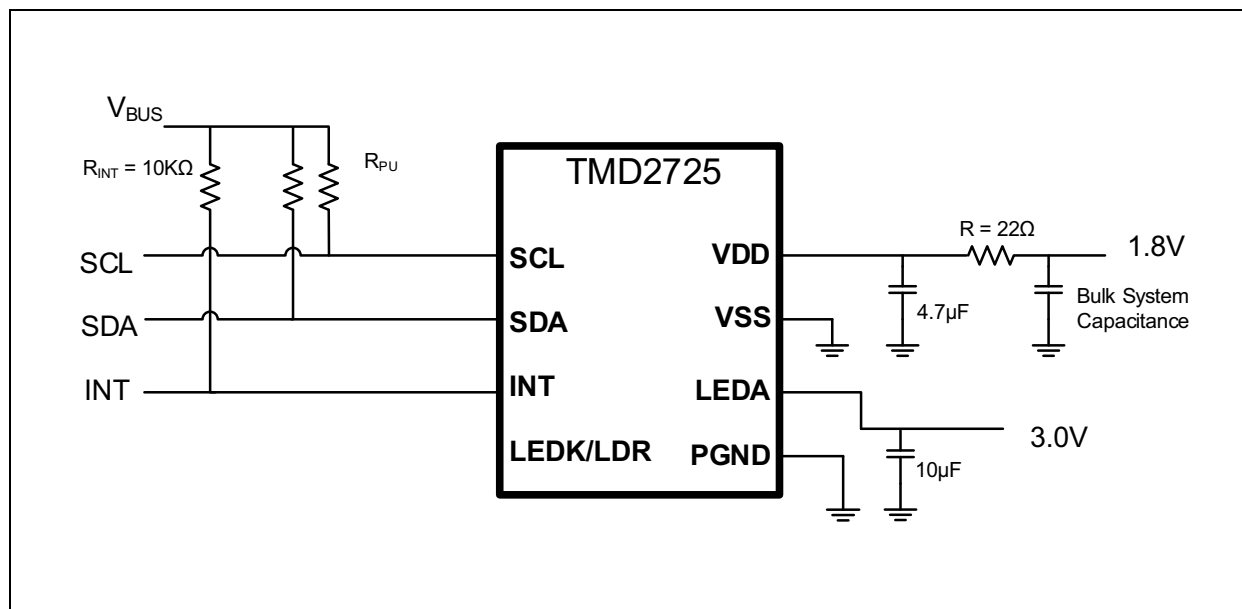
**Figure 52:**  
**INTENAB Register**

Addr: 0xDD		INTENAB		
Bit	Bit Name	Default	Access	Bit Description
7	ASIEN	0	RW	ALS Saturation Interrupt Enable
6	PSIEN	0	RW	Proximity Saturation Interrupt Enable
5	PIEN	0	RW	Proximity Interrupt Enable
4	AIEN	0	RW	ALS Interrupt Enable
3	CIEN	0	RW	Calibration Interrupt Enable
2:0	Reserved	000	RW	Reserved

## Application Information

### Schematic

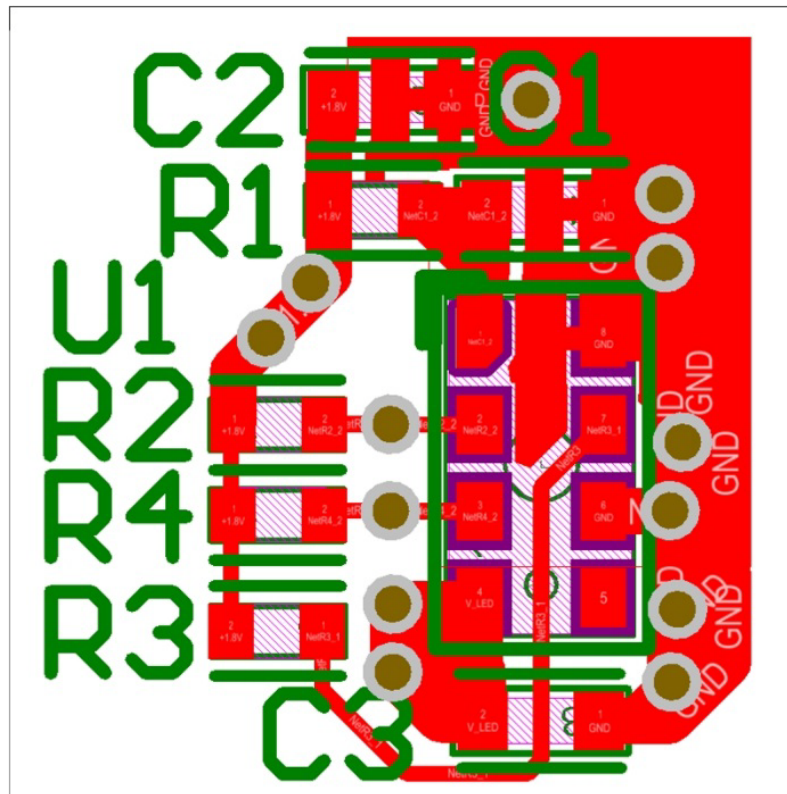
**Figure 53:**  
Typical Applications Circuit



**Typical Applications Circuit:** It is important to place the  $4.7\mu F$  (VDD) and  $10\mu F$  (LEDK) capacitors at the package pins.

## PCB Layout

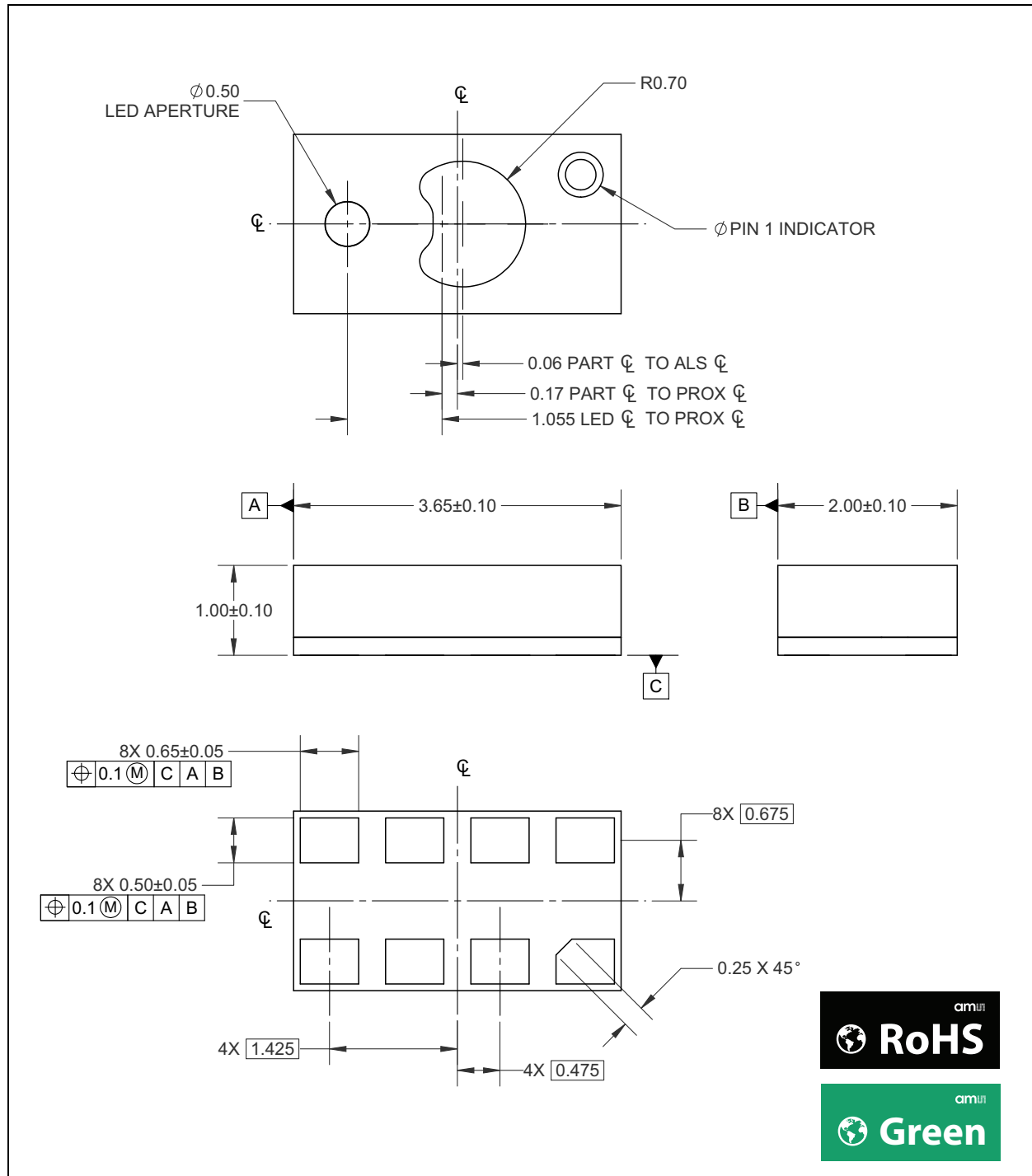
**Figure 54:**  
Typical Applications Circuit



The dominant factor governing device performance is the component placement, not necessarily component value. The placement of the decoupling capacitor, C1, is the most critical. Place the component on the same side of PCB as device as shown in the figure above. Make connection as close as possible to minimize series inductance and resistance. This is critical.

## Package Drawings & Markings

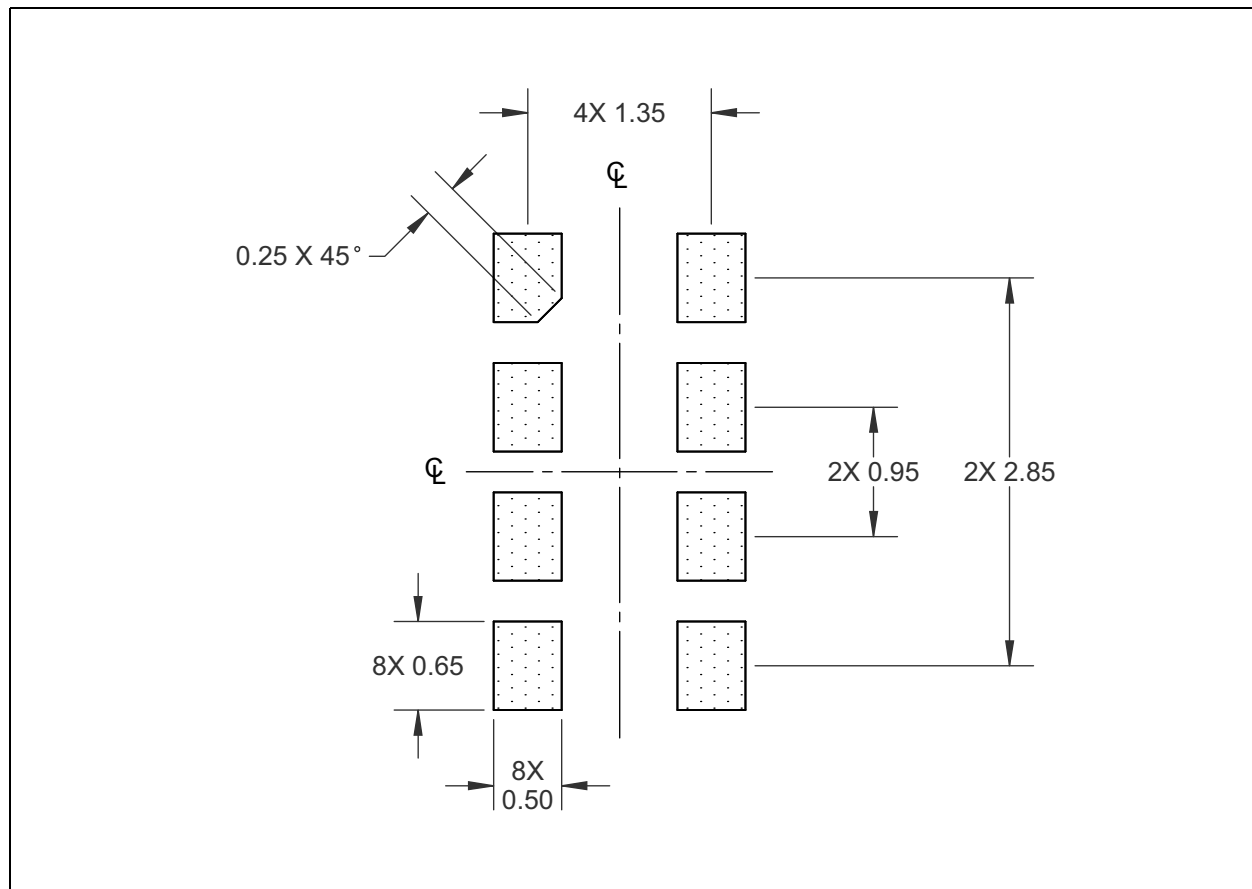
**Figure 55:**  
Package Drawings



**Note(s):**

1. All linear dimensions are in millimeters.
2. Contact finish is Au.
3. This package contains no lead (Pb).
4. This drawing is subject to change without notice.

**Figure 56:**  
**Recommended PCB Layout**



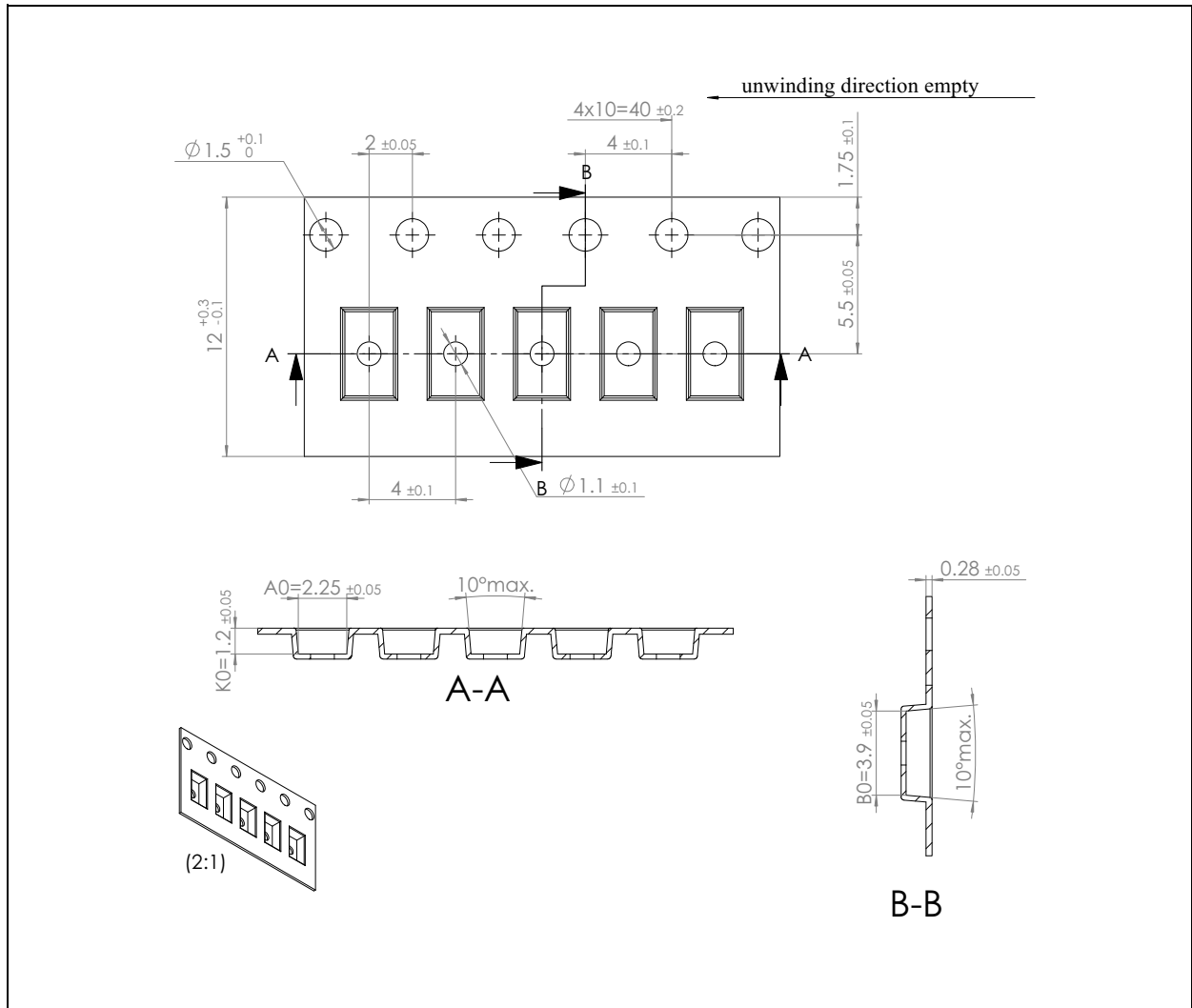
**Note(s):**

1. All dimensions are in millimeters.
2. Dimension tolerances are 0.05mm unless otherwise noted.
3. This drawing is subject to change without notice.



## Tape & Reel Information

**Figure 57:**  
Tape and Reel Information



**Note(s):**

1. All linear dimensions are in millimeters.
2. For missing tolerances and dimensions, refer to EIA-481.
3. In accordance with EIA standard, device pin 1 is located next to the sprocket holes in the tape.

## Soldering & Storage Information

The module has been tested and has demonstrated an ability to be reflow soldered to a PCB substrate. The solder reflow profile describes the expected maximum heat exposure of components during the solder reflow process of product on a PCB. Temperature is measured on top of component. The components should be limited to a maximum of three passes through this solder reflow profile.

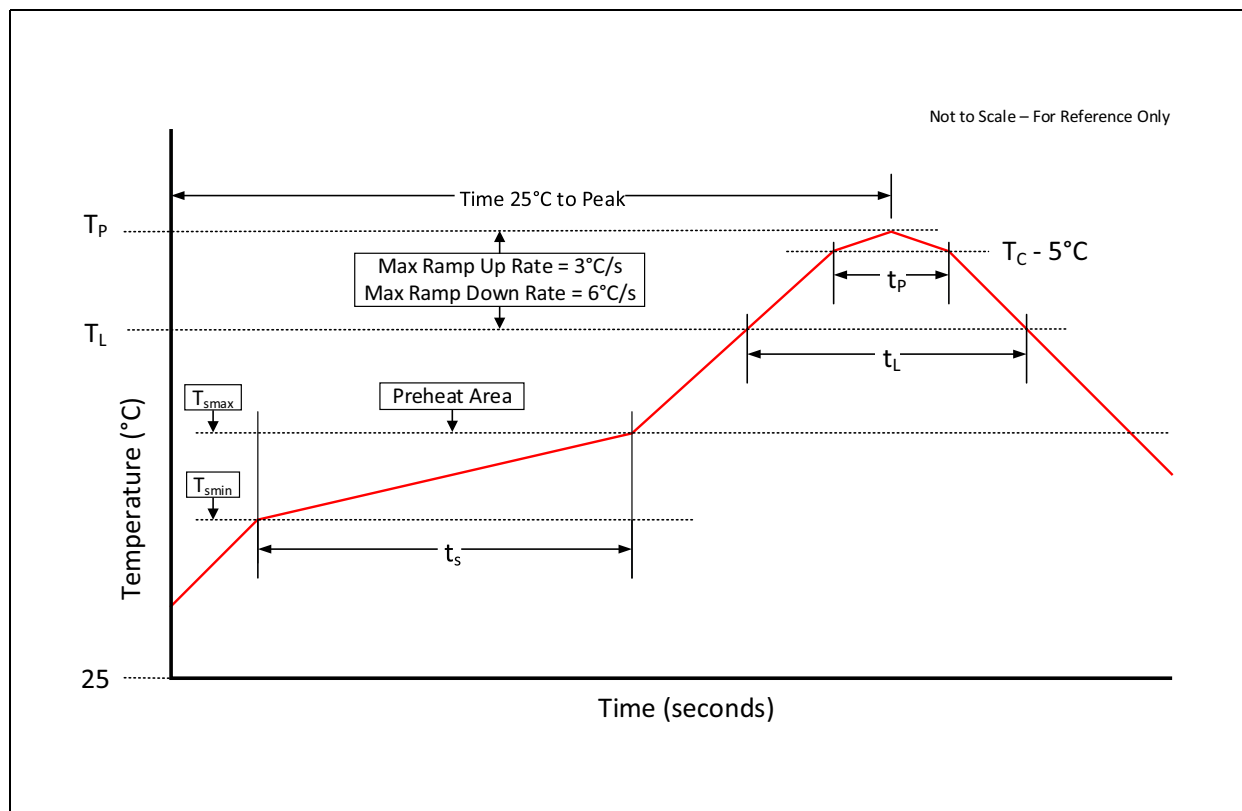
**Figure 58:**  
**Solder Reflow Profile**

Profile Feature Preheat/ Soak	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Temperature Min ( $T_{smin}$ )	100 °C	150 °C
Temperature Max ( $T_{smax}$ )	150 °C	200 °C
Time ( $t_s$ ) from ( $T_{smin}$ to $T_{smax}$ )	60-120 seconds	60-120 seconds
Ramp-up rate ( $T_L$ to $T_P$ )	3 °C/second max.	3 °C/second max.
Liquidous temperature ( $T_L$ ) Time ( $t_L$ ) maintained above $T_L$	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak package body temperature ( $T_P$ )	For users $T_P$ must not exceed the Classification temp of 235 °C For suppliers $T_P$ must equal or exceed the Classification temp of 235 °C	For users $T_P$ must not exceed the Classification temp of 260 °C For suppliers $T_P$ must equal or exceed the Classification temp of 260 °C
Time ( $t_p$ ) <sup>(1)</sup> within 5 °C of the specified classification temperature ( $T_C$ )	20 <sup>(1)</sup> seconds	30 <sup>(1)</sup> seconds
Ramp-down rate ( $T_P$ to $T_L$ )	6 °C/second max.	6 °C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

**Note(s):**

1. Tolerance for peak profile temperature (TP) is defined as a supplier minimum and a user maximum.

**Figure 59:**  
**Solder Reflow Profile Graph**



## Storage Information

Moisture Sensitivity Optical characteristics of the device can be adversely affected during the soldering process by the release and vaporization of moisture that has been previously absorbed into the package. To ensure the package contains the smallest amount of absorbed moisture possible, each device is baked prior to being dry packed for shipping. Devices are dry packed in a sealed aluminized envelope called a moisture-barrier bag with silica gel to protect them from ambient moisture during shipping, handling, and storage before use.

## Shelf Life

The calculated shelf life of the device in an unopened moisture barrier bag is 24 months from the date code on the bag when stored under the following conditions:

- Shelf Life: 24 months
- Ambient Temperature: <40°C
- Relative Humidity: <90%

Rebaking of the devices will be required if the devices exceed the 24 months shelf life and the Humidity Indicator Card shows that the devices were exposed to conditions beyond the allowable moisture region.

## Floor Life

The module has been assigned a moisture sensitivity level of MSL 3. As a result, the floor life of devices removed from the moisture barrier bag is 168 hours from the time the bag was opened, provided that the devices are stored under the following conditions:

- Floor Life: 168 hours
- Ambient Temperature: <30°C
- Relative Humidity: <60%

If the floor life or the temperature/humidity conditions have been exceeded, the devices must be rebaked prior to solder reflow or dry packing.

## Rebaking Instructions

When the shelf life or floor life limits have been exceeded, rebake at 50°C for 12 hours.

## Ordering & Contact Information

Figure 60:  
Ordering Information

Ordering Code	I <sup>2</sup> C Bus	I <sup>2</sup> C Address	Delivery Form	Delivery Quantity
TMD27253M	1.8V	39h	Tape & Reel (7")	1000 pcs/reel
TMD27253			Tape & Reel (13")	10000 pcs/reel

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### Headquarters

ams-OSRAM AG  
Tobelbader Strasse 30  
8141 Premstaetten  
Austria, Europe

Tel: +43 (0) 3136 500 0

Website: [www.ams.com](http://www.ams.com)

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Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
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## Revision Information

Changes from 1-13 (2018-Feb-23) to current revision 2-00 (2023-Feb-22)	Page
Updated “Shelf Life” to 24 months	42

**Note(s):**

1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
2. Correction of typographical errors is not explicitly mentioned.

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28	Status Register (Address 0x93)
28	PHOTOPICL Register (Address 0x94)
29	PHOTOPICH Register (Address 0x95)
29	ALS_IRL Register (Address 0x96)
29	ALS_IRH Register (Address 0x97)
29	PDATA Register (Address 0x9C)
30	REVID2 Register (Address 0x9E)
30	CFG2 Register (Address 0x9F)
31	CFG3 Register (Address 0xAB)
32	POFFSETL Register (Address 0xC0)
32	POFFSETH Register (Address 0xC1)
33	AZ_CONFIG Register (Address 0xD6)
33	CALIB Register (Address 0xD7)

34	CALIBCFG Register (Address 0xD9)
35	CALIBSTAT Register (Address 0xDC)
35	INTENAB Register (Address 0xDD)
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